Product Datasheet
Graphenea Monolayer Graphene film on Cu

|  | Graphene Film |  |
| :--- | :--- | :---: |
| Growth Method | CVD synthesis |  |
| Transfer Method | Clean transfer method |  |
| Quality Control | Optical Microscopy \& Raman checked |  |
| Appearance (Color) | Transparent |  |
| Transparency | $>97 \%$ |  |
| Appearance (Form) | Film |  |
| Coverage | $>95 \%$ |  |
| Number of graphene layers | 1 |  |
| Thickness (theoretical) | 0.345 nm |  |
| AFM Thickness (air @RT) | $<1 \mathrm{~nm}$ |  |
| Electron Mobility on SiO $2 / \mathrm{Si}$ | $\approx 1500 \mathrm{~cm} 2 / \mathrm{V} \cdot \mathrm{s}$ |  |
| Sheet Resistance on $\mathrm{SiO} 2 / \mathrm{Si}$ (Van der Pauw) | $450 \pm 40 \mathrm{Ohms} / \mathrm{sq}.(1 \mathrm{~cm} \times 1 \mathrm{~cm})$ |  |
| Sheet Resistance PEN (Van der Pauw) | $750 \pm 50 \mathrm{Ohms} / \mathrm{sq}.(1 \mathrm{~cm} \times 1 \mathrm{~cm})$ |  |
| Sheet Resistance Quartz (Van der Pauw) | $360 \pm 50 \mathrm{Ohms} / \mathrm{sq} .(1 \mathrm{~cm} \times 1 \mathrm{~cm})$ |  |
| Grain size | Up to $20 \mathrm{\mu m}$ |  |

Substrates

## Cu foil

| Thickness | $18 \mu \mathrm{~m}$ |
| :--- | :--- |
| Roughness | 80 nm |

Note: Pretreated for easier bottom layer removal

## - Graphenea



Monolayer Graphene on Cu


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Laser wavelength: 457 nm


Suspended graphene on TEM grids

